

**100V PNP LOW VCESAT TRANSISTOR IN PowerDI3333-8** 

#### Features

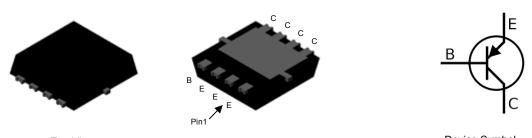
- BV<sub>CEO</sub> > -100V
- Small Form Factor Thermally Efficient Package. Enables Higher Density End Products
- I<sub>C</sub> = -5A Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -90mV @ -1A •
- $R_{SAT}$  = 56m $\Omega$  for a Low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: DXTN03100BFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.03 grams (Approximate)

### Applications

- Motor Driving
- Line Switching
- **High Side Switches**



Top View

Bottom View

Device Symbol

### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTP03100BFG-7	2J9	7	12	2000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

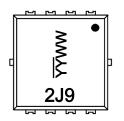
4. For packaging details, go to our website at https://www.diodes.com/products/packages.html.

PowerDI3333-8 (SWP) (Type UX)

### Marking Information

Notes:

PowerDI3333-8 (SWP) (Type UX)



2J9= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-140	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ιc	-5	А
Peak Pulse Current	I <sub>CM</sub>	-10	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.07	W
Power Dissipation	(Note 6)	PD	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>OJA</sub>	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8)		R <sub>θJL</sub>	6	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C	

# ESD Ratings (Note 9)

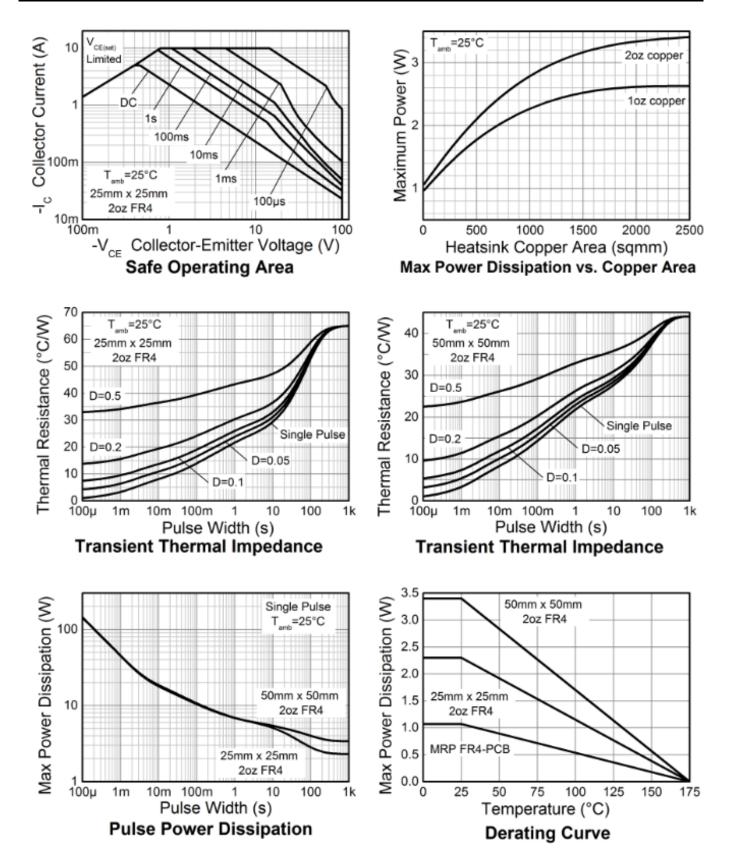
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

 For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.
Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper. Notes:

Thermal resistance from junction to solder-point (at the collector tab).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





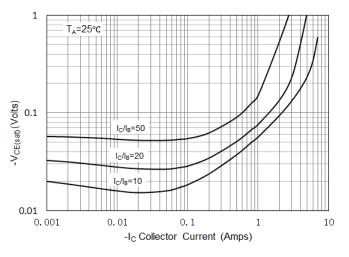
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-140	-169		V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage	BVCER	-140	-167		V	I <sub>C</sub> = -1μA, RB ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-100	-125	_	V	$I_{\rm C}$ = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.4	_	V	I <sub>E</sub> = -100μA
Collector-Base Cut-Off Current			-2	-50	nA	V <sub>CB</sub> = -100V
Collector-Base Cut-Off Current	ICBO	_	-0.1	-10	μA	V <sub>CB</sub> = -100V, T <sub>A</sub> = +125°C
Collector-Emitter Cut-Off Current	ICER	_	-2	-50	nA	V <sub>CB</sub> = -100V
	R ≤ 1kΩ	-	-0.3	-10	μA	V <sub>CB</sub> = -100V, T <sub>A</sub> = +125°C
Emitter Cut-Off Current	I <sub>EBO</sub>	_	1	-20	nA	V <sub>EB</sub> = -6V
		100	172	_	_	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V
		100	151	300	_	$I_{C}$ = -1A, $V_{CE}$ = -2V
Static Forward Current Transfer Ratio (Note 10)	h <sub>FE</sub>	25	43	—	—	$I_{C}$ = -3A, $V_{CE}$ = -2V
		15	27	—	—	$I_{C}$ = -4A, $V_{CE}$ = -2V
		5	7.3	_	_	I <sub>C</sub> = -10A, V <sub>CE</sub> = -2V
	V <sub>CE(sat)</sub>	_	-18	-30	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
Collector Emitter Seturation Voltage (Note 10)		-	-56	-90	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Collector-Emitter Saturation Voltage (Note 10)		_	-94	-150	mV	I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
		_	-177	-340	mV	I <sub>C</sub> = -4A, I <sub>B</sub> = -400mA
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	_	-967	-1100	mV	I <sub>C</sub> = -4A, I <sub>B</sub> = -400mV
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	-	-869	-950	mV	$I_{\rm C}$ = -4A, $V_{\rm CE}$ = -2V
Output Capacitance	Cobo	_	42	_	pF	V <sub>CB</sub> = -10V. f = 1MHz
Transition Frequency	f <sub>T</sub>	_	125	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -100mA f = 50MHz
	t <sub>delay</sub>	-	10.1	_	ns	
Switching Characteristics	t <sub>rise</sub>		181	_	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -1A
Switching Characteristics	t <sub>storage</sub>		1340	_	ns	I <sub>B1</sub> = I <sub>B2</sub> = -100mA
	t <sub>fall</sub>		127		ns	

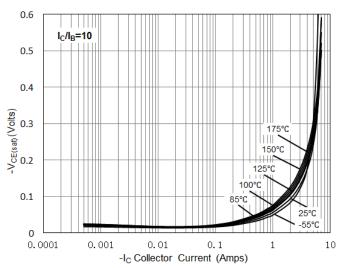
Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



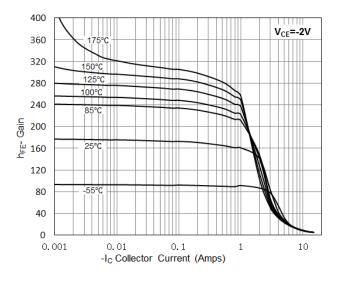
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



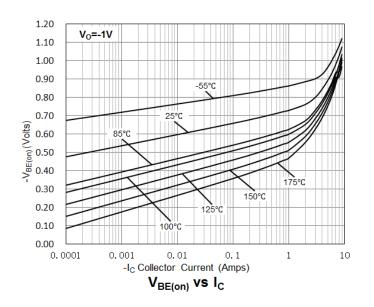
V<sub>CE(sat)</sub> vs I<sub>C</sub>

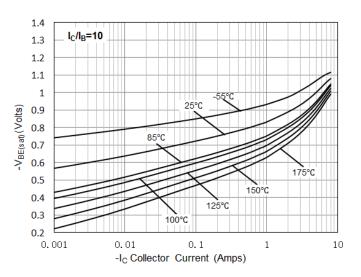


V<sub>CE(sat)</sub> vs I<sub>C</sub>









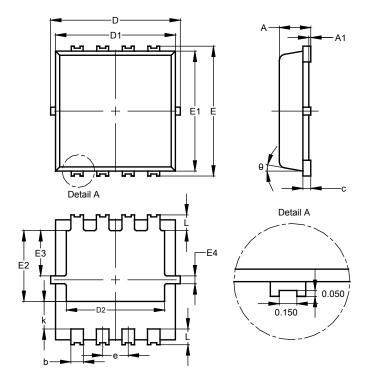
V<sub>BE(sat)</sub> vs I<sub>C</sub>



## **Package Outline Dimensions**

Please see https://www.diodes.com/package-outlines.html for the latest version.

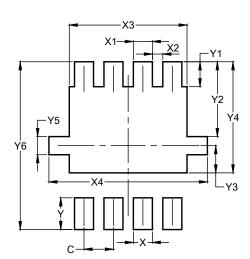
#### PowerDI3333-8 (SWP) (Type UX)



PowerDI3333-8 (SWP)						
	(Type UX)					
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е		_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All I	All Dimensions in mm					

## **Suggested Pad Layout**

Please see https://www.diodes.com/package-outlines.html for the latest version.



#### PowerDI3333-8 (SWP) (Type UX)

Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
X3	2.600		
X4	3.500 0.700		
Y			
Y1	0.550		
Y2	1.650		
Y3	0.600		
Y4	2.450		
Y5	0.400		
Y6	3.700		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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